

Excellent Integrated System Limited

Stocking Distributor

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[OSRAM Opto Semiconductors, Inc.](#)
[SFH 4248-Z](#)

For any questions, you can email us directly:

sales@integrated-circuit.com

High Power Infrared Emitter (940 nm) Version 1.3/ OS-IN-2015-033

SFH 4248



Features:

- High Power Infrared LED
- Short switching times
- Half angle: $\pm 15^\circ$
- High forward current allowed at high temperature
- The product qualification test plan is based on the guidelines of AEC-Q101-REV-C, Stress Test Qualification for Automotive Grade Discrete Semiconductors.

Applications

- Infrared Illumination for cameras
- IR data transmission
- Sensor technology

Notes

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

Ordering Information

Type:	Radiant Intensity I_e [mW/sr] $I_F = 100 \text{ mA}$, $t_p = 20 \text{ ms}$	Ordering Code
SFH 4248	100 (≥ 40)	Q65110A7518

Note: Measured at a solid angle of $\Omega = 0.01 \text{ sr}$

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Maximum Ratings ($T_A = 25\text{ }^{\circ}\text{C}$)

Parameter	Symbol	Values	Unit
Operation and storage temperature range	$T_{op}; T_{stg}$	-40 ... 100	$^{\circ}\text{C}$
Reverse voltage	V_R	5	V
Forward current	I_F	100	mA
Surge current ($t_p = 100\text{ }\mu\text{s}$, $D = 0$)	I_{FSM}	1	A
Power consumption	P_{tot}	180	mW
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	V_{ESD}	2	kV
Thermal resistance junction - ambient ^{1) page 12}	R_{thJA}	300	K / W
Thermal resistance junction - soldering point ^{2) page 12}	R_{thJS}	140	K / W

Characteristics ($T_A = 25\text{ }^{\circ}\text{C}$)

Parameter	Symbol	Values	Unit
Peak wavelength ($I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$)	λ_{peak}	950	nm
Centroid wavelength ($I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$)	$\lambda_{centroid}$	940	nm
Spectral bandwidth at 50% of I_{max} ($I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$)	$\Delta\lambda$	42	nm
Half angle	ϕ	± 15	$^{\circ}$
Dimensions of active chip area	L x W	0.3 x 0.3	mm x mm
Rise and fall time of I_e (10% and 90% of $I_{e\text{ max}}$) ($I_F = 100\text{ mA}$, $R_L = 50\text{ }\Omega$)	t_r, t_f	12	ns
Forward voltage ($I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$)	V_F	1.5 (≤ 1.8)	V
Forward voltage ($I_F = 1\text{ A}$, $t_p = 100\text{ }\mu\text{s}$)	V_F	2.3 (≤ 3)	V
Reverse current ($V_R = 5\text{ V}$)	I_R	not designed for reverse operation	μA
Total radiant flux ($I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$)	Φ_e	65	mW

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Parameter		Symbol	Values	Unit
Temperature coefficient of I_e or Φ_e ($I_F = 100$ mA, $t_p = 20$ ms)	(typ)	TC_I	-0.5	% / K
Temperature coefficient of V_F ($I_F = 100$ mA, $t_p = 20$ ms)	(typ)	TC_V	-1.3	mV / K
Temperature coefficient of wavelength ($I_F = 100$ mA, $t_p = 20$ ms)	(typ)	TC_λ	0.3	nm / K

Grouping ($T_A = 25^\circ\text{C}$)

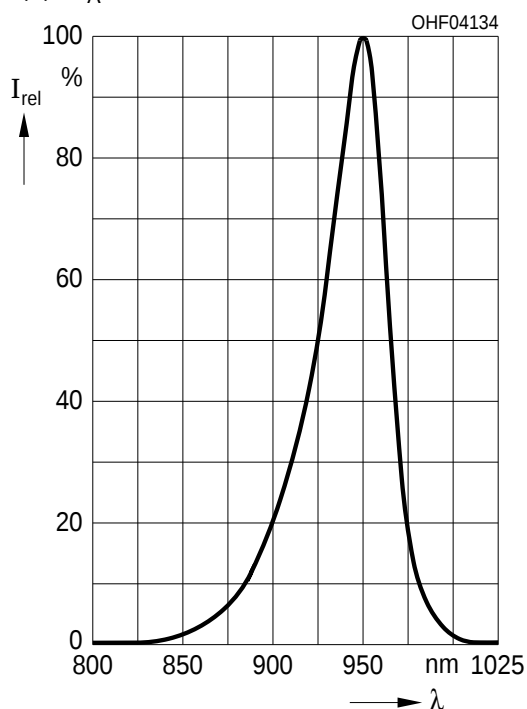
Group	Min Radiant Intensity $I_F = 100$ mA, $t_p = 20$ ms $I_{e, \min}$ [mW / sr]	Max Radiant Intensity $I_F = 100$ mA, $t_p = 20$ ms $I_{e, \max}$ [mW / sr]	Typ Radiant Intensity $I_F = 1$ A, $t_p = 25$ μ s $I_{e, \text{typ}}$ [mW / sr]
SFH 4248-U	40	80	420
SFH 4248-V	63	125	750
SFH 4248-AW	100	200	1100

Note: measured at a solid angle of $\Omega = 0.01$ sr

Only one group in one packing unit (variation lower 2:1).

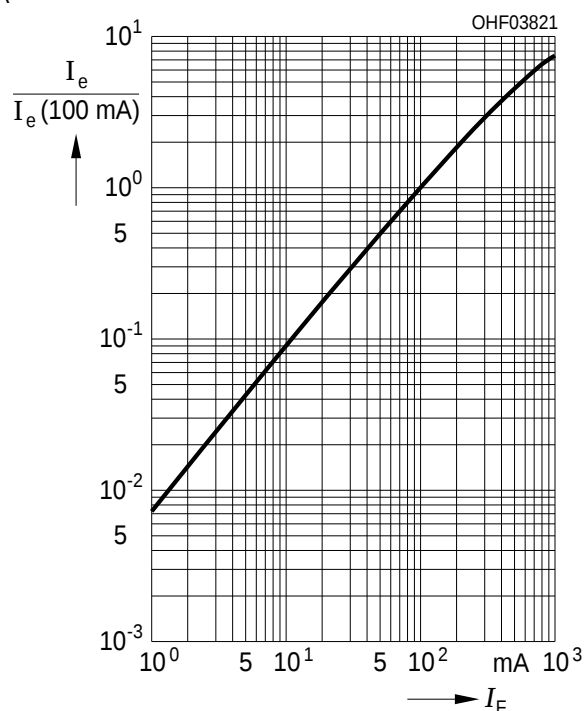
Relative Spectral Emission ^{3) page 12}

$I_{\text{rel}} = f(\lambda)$, $T_A = 25^\circ\text{C}$



Radiant Intensity ^{3) page 12}

$I_e / I_e(100 \text{ mA}) = f(I_F)$, single pulse, $t_p = 25$ μ s,
 $T_A = 25^\circ\text{C}$

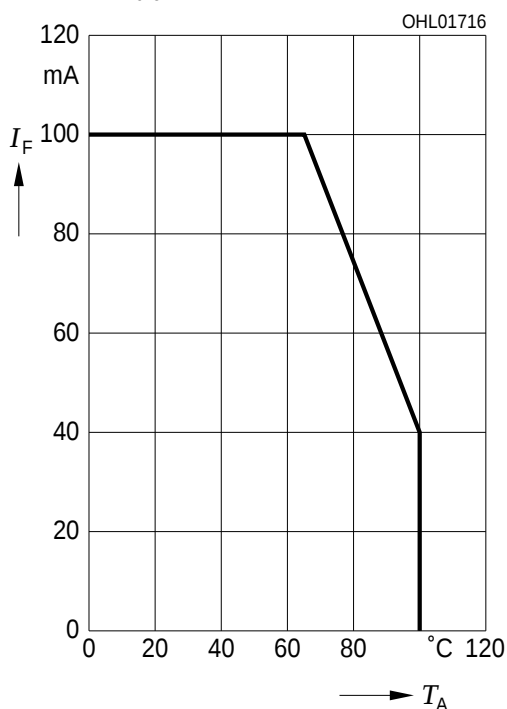


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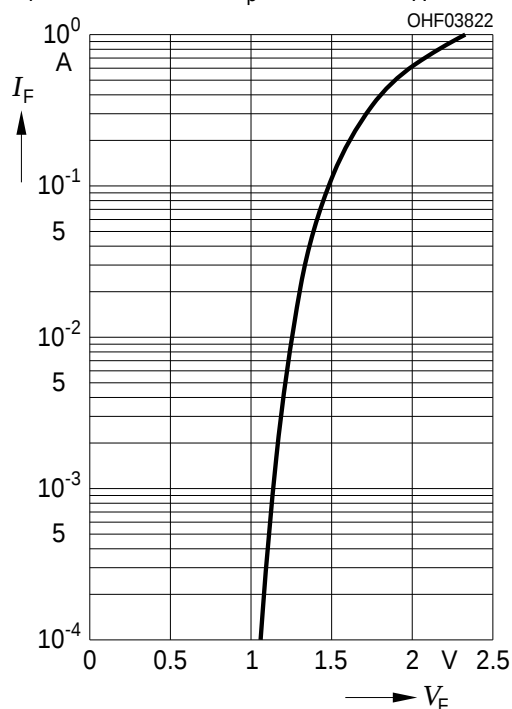
Max. Permissible Forward Current

$$I_{F, \max} = f(T_A), R_{thJA} = 300 \text{ K / W}$$



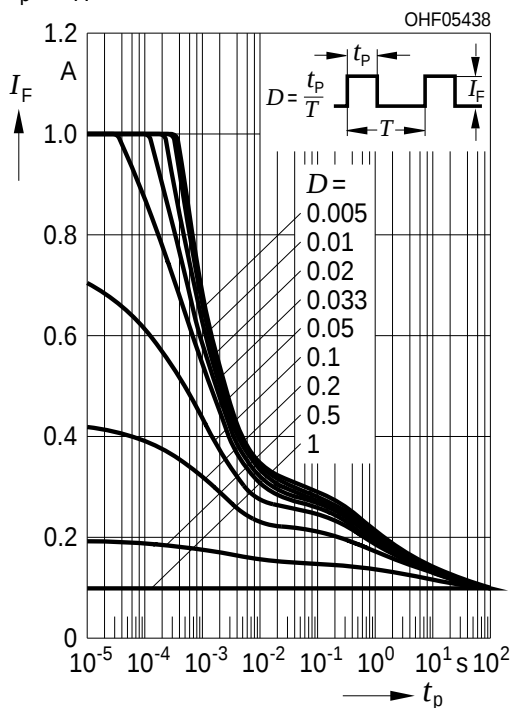
Forward Current ^{3) page 12}

$$I_F = f(V_F), \text{ single pulse, } t_p = 100 \mu\text{s}, T_A = 25^\circ\text{C}$$



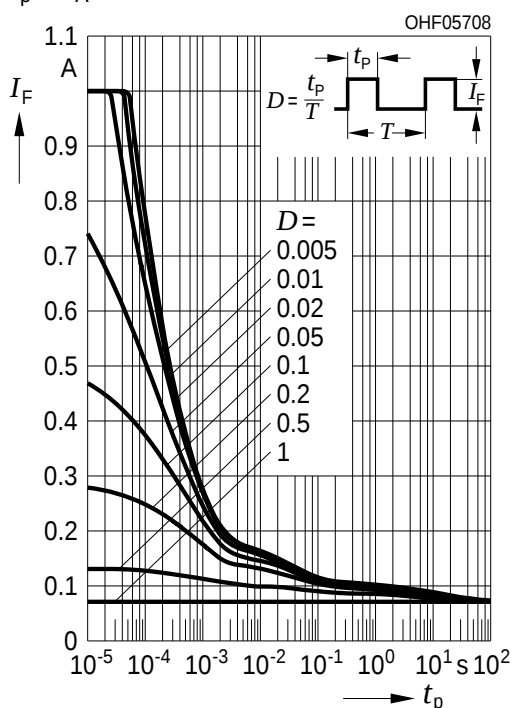
Permissible Pulse Handling Capability

$$I_F = f(t_p), T_A = 25^\circ\text{C}, \text{ duty cycle } D = \text{parameter}$$



Permissible Pulse Handling Capability

$$I_F = f(t_p), T_A = 85^\circ\text{C}, \text{ duty cycle } D = \text{parameter}$$

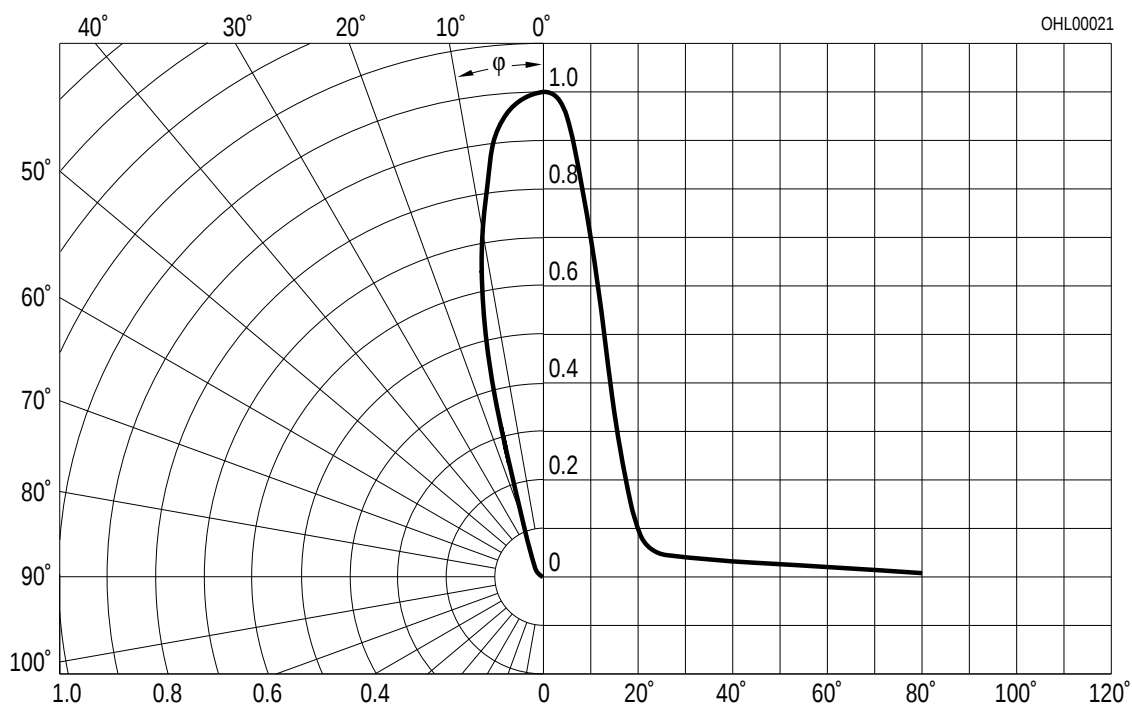


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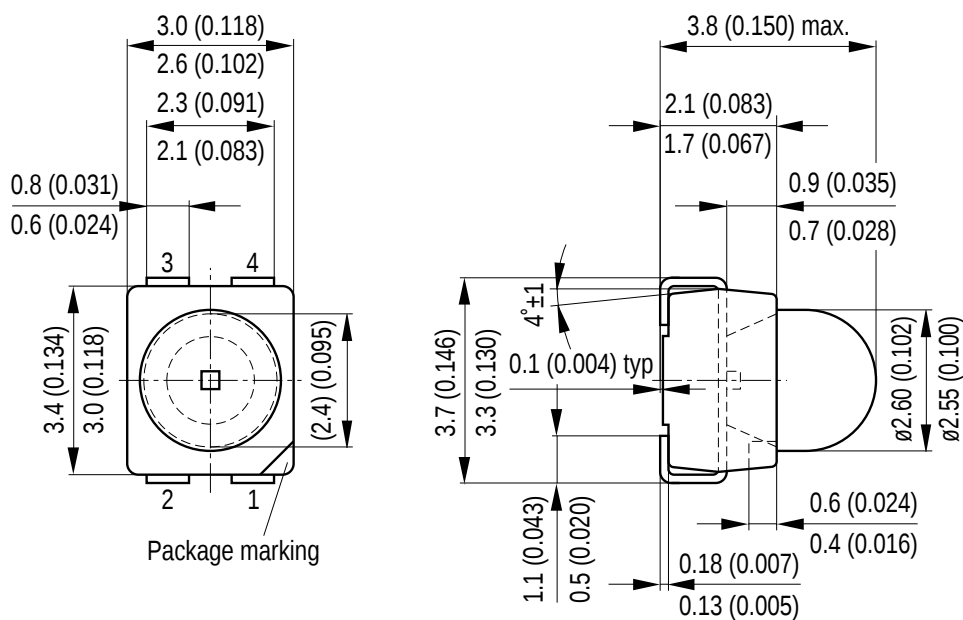
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Radiation Characteristics ^{3) page 12}

$$I_{\text{rel}} = f(\phi)$$



Package Outline



Dimensions in mm (inch).

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Pinning

Pin	Description
1	Cathode
2	Anode
3	Anode
4	Anode

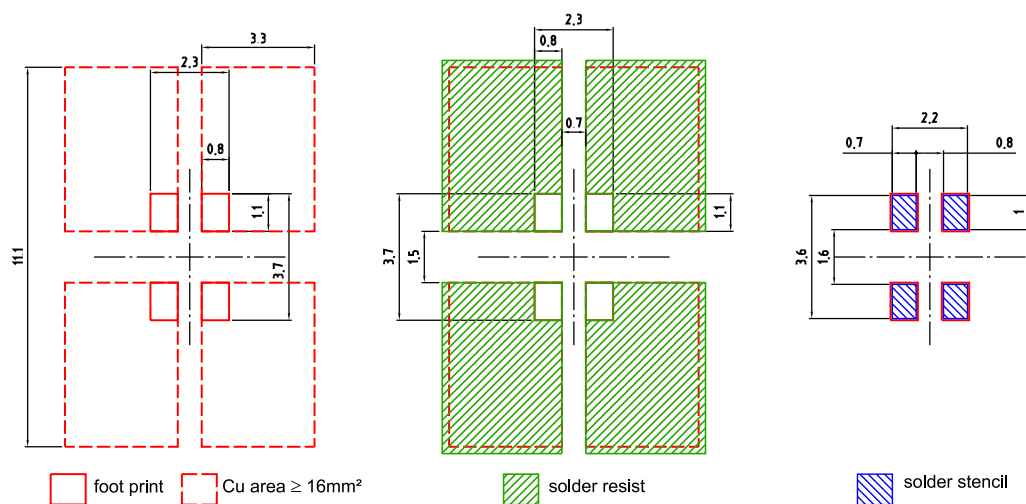
Package

Power TOPLED with Lens

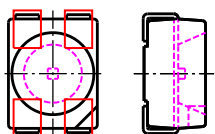
Approximate Weight:

37 mg

Recommended Solder Pad



Component Location on Pad



Dimensions in mm.

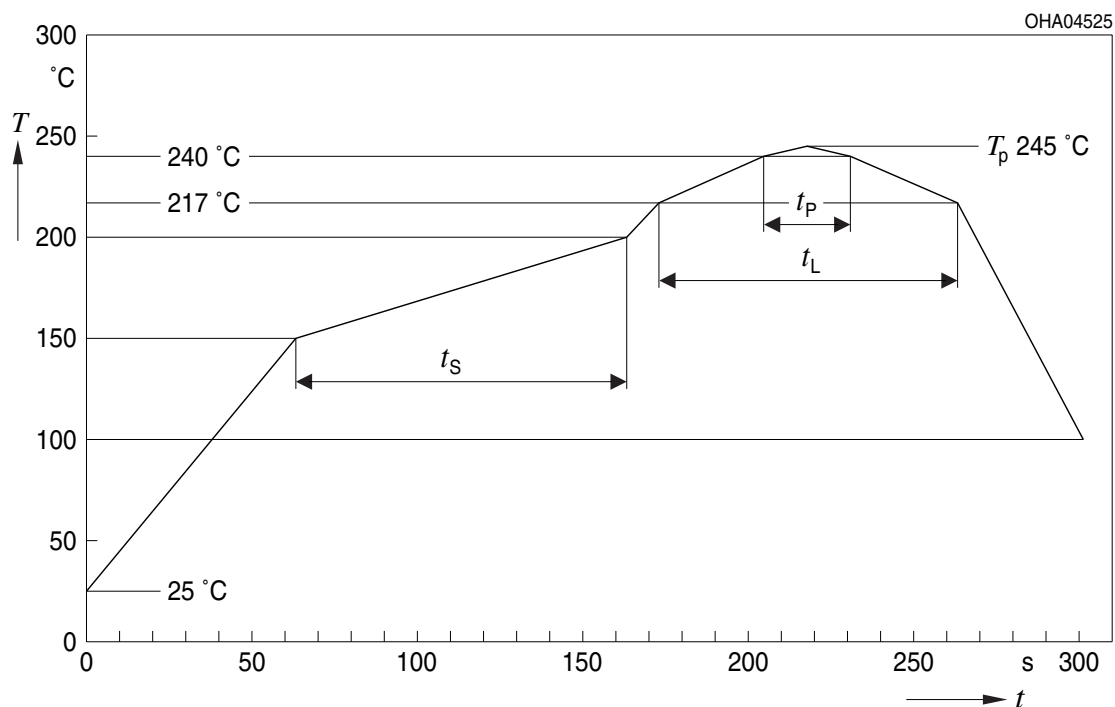
E062.3010.28-01

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Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020D.01



Profil-Charakteristik Profile Feature	Symbol Symbol	Pb-Free (SnAgCu) Assembly			Einheit Unit
		Minimum	Recommendation	Maximum	
Ramp-up Rate to Preheat*) 25 °C to 150 °C			2	3	K/s
Time t_S T_{Smin} to T_{Smax}	t_S	60	100	120	s
Ramp-up Rate to Peak*) T_{Smax} to T_P			2	3	K/s
Liquidus Temperature	T_L	217			$^{\circ}\text{C}$
Time above Liquidus temperature	t_L		80	100	s
Peak Temperature	T_P		245	250	$^{\circ}\text{C}$
Time within 5 °C of the specified peak temperature $T_P - 5\text{ K}$	t_P	10	20	30	s
Ramp-down Rate* T_P to 100 °C			3	4	K/s
Time 25 °C to T_P				480	s

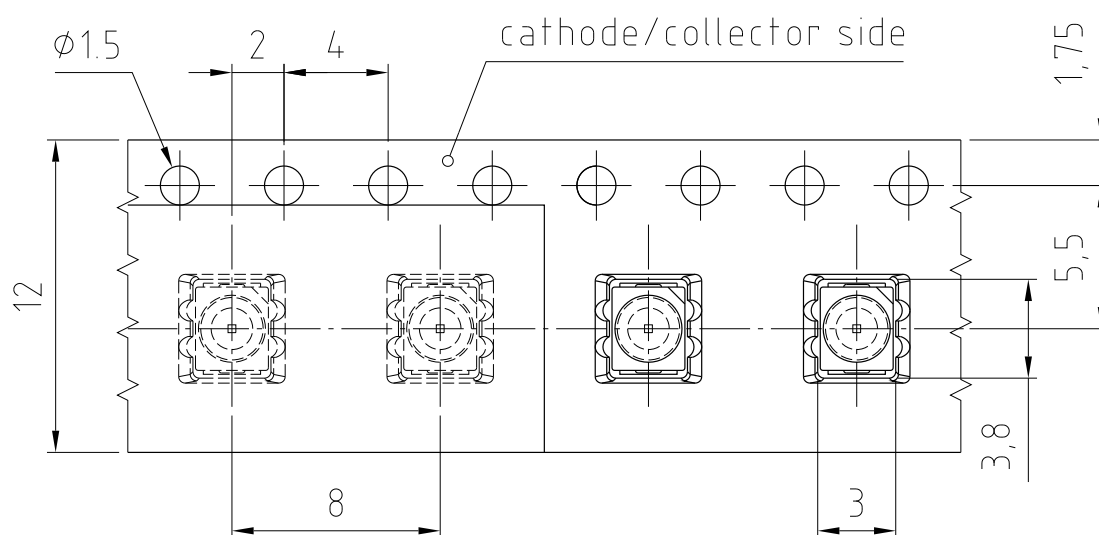
All temperatures refer to the center of the package, measured on the top of the component

* slope calculation DT/Dt : Dt max. 5 s; fulfillment for the whole T-range

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Taping

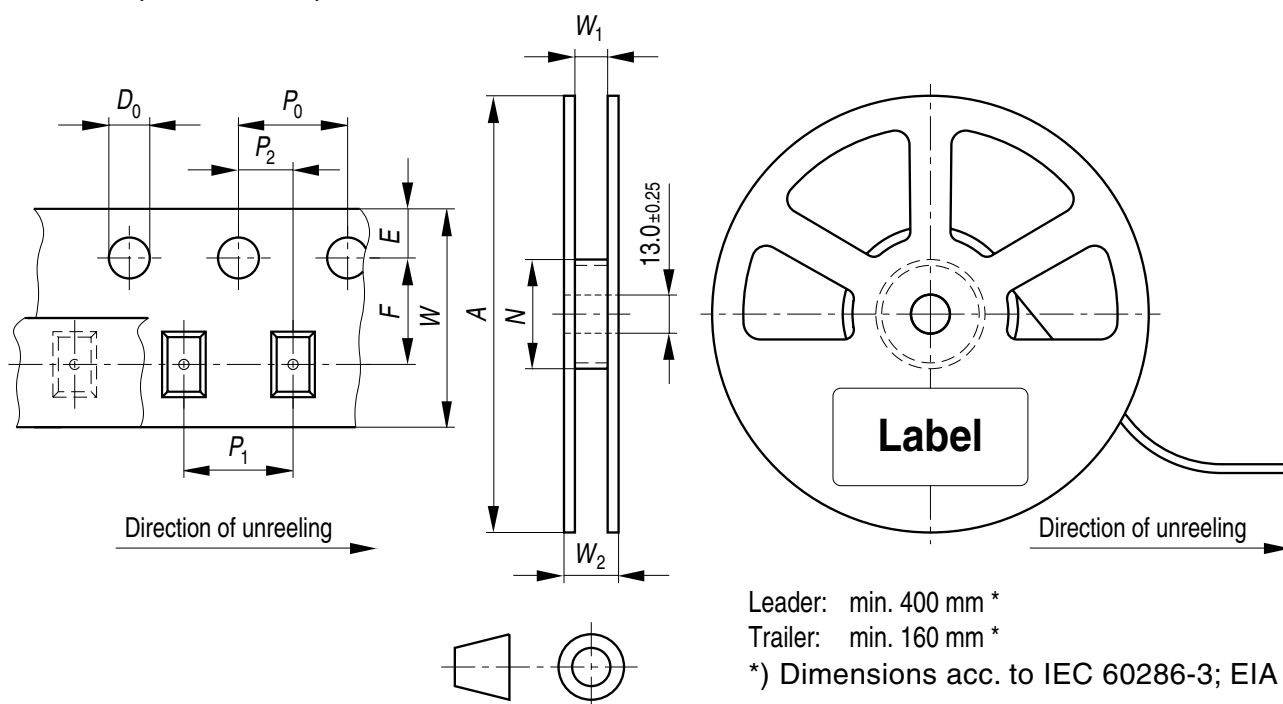


C63062-A3636-B4-03

Dimensions in mm.

Tape and Reel

12 mm tape with 2000 pcs. on ϕ 180 mm reel



Leader: min. 400 mm *

Trailer: min. 160 mm *

*) Dimensions acc. to IEC 60286-3; EIA 481-D

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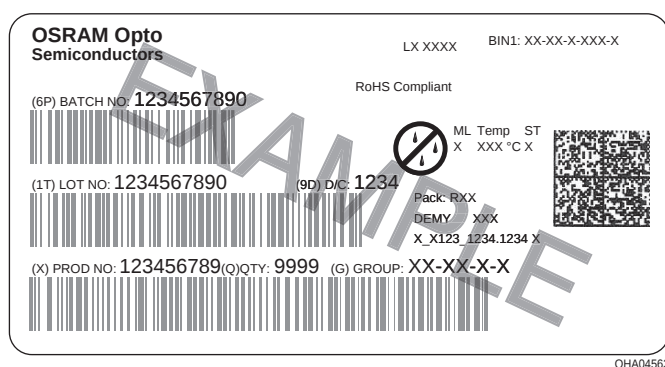
Tape dimensions [mm]

W	P ₀	P ₁	P ₂	D ₀	E	F
12 ± 0.3 / - 0.1	4 ± 0.1	4 ± 0.1 or 8 ± 0.1	2 ± 0.05	1.5 ± 0.1	1.75 ± 0.1	5.5 ± 0.05

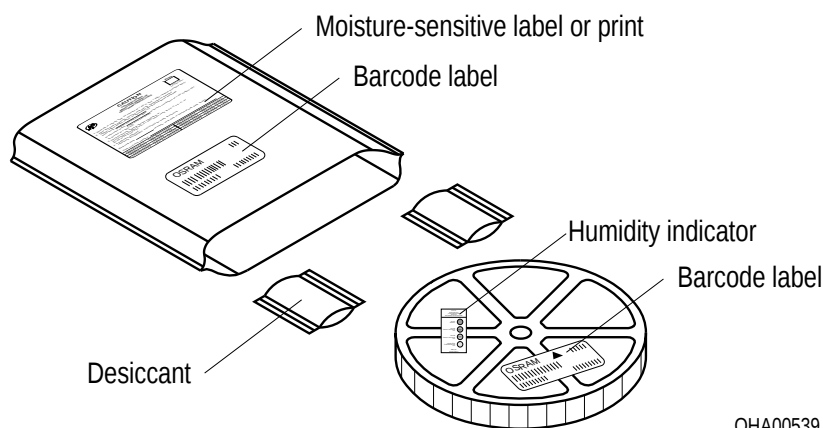
Reel dimensions [mm]

A	W	N _{min}	W ₁	W _{2max}
180	12	60	12.4 ± 2	18.4

Barcode-Product-Label (BPL)



Dry Packing Process and Materials



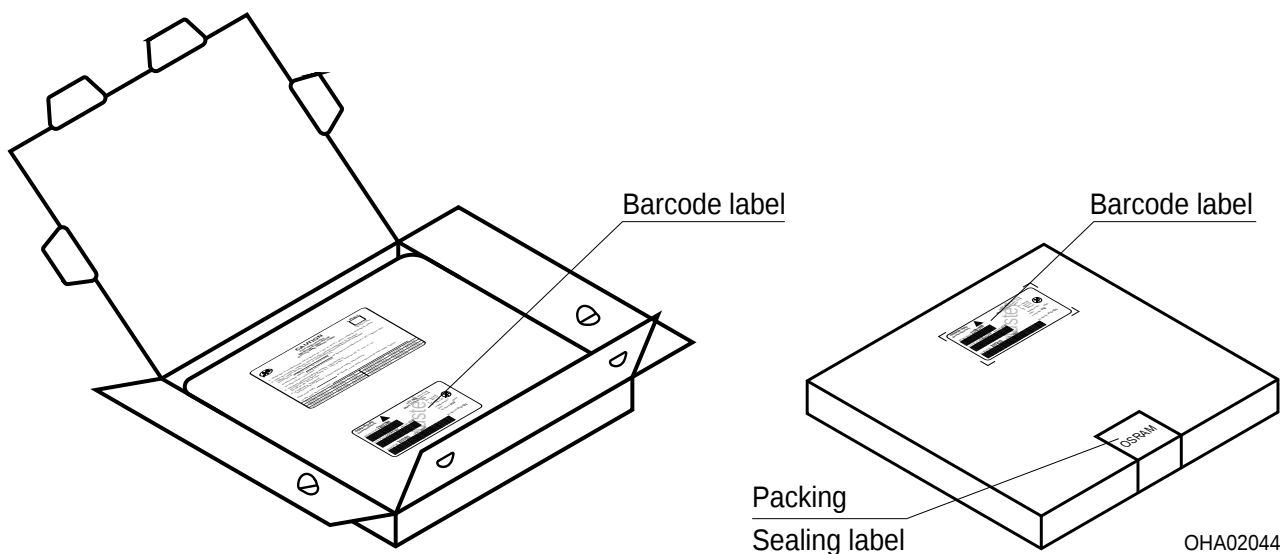
Note:

Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card. Regarding dry pack you will find further information in the internet. Here you will also find the normative references like JEDEC.

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Transportation Packing and Materials



Dimensions of transportation box in mm

Width	Length	Height
195 ± 5	195 ± 5	30 ± 5

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Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the Internet.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office.

By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Components used in life-support devices or systems must be expressly authorized for such purpose!

Critical components* may only be used in life-support devices** or systems with the express written approval of OSRAM OS.

*) A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.

**) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.

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Glossary

- ¹⁾ **Thermal resistance:** junction -ambient, mounted on PC-board (FR4), padsize 16 mm² each
- ²⁾ **Thermal resistance:** junction - soldering point, of the device only, mounted on an ideal heatsink (e.g. metal block)
- ³⁾ **Typical Values:** Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

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